Electric Field Effects on Photoluminescence-Detected Magnetic Resonance of a π-Conjugated Polymer


Electric fields are central to the operation of optoelectronic devices based on conjugated polymers as they drive the recombination of electrons and holes to excitons in organic light-emitting diodes but are also responsible for the dissociation of excitons in solar cells. One way to track the microscopic effect of electric fields on charge carriers formed under illumination of a polymer film is to exploit the fluorescence arising from delayed recombination of carrier pairs, a process which is fundamentally spin dependent. Such spin-dependent recombination can be probed directly in fluorescence, by optically detected magnetic resonance (ODMR). It is found that the ODMR signal in a polymer film is quenched in an electric field in the absence of a current, but that, at fields exceeding 1 MV cm⁻¹, this quenching saturates at a level of at most 50%.

1. Introduction

One of the longest-standing puzzles in photophysical phenomena in π-conjugated polymers is the process of charge generation following optical excitation.[1] Photoexcitation typically leads to the population of a higher-lying intramolecular excited state of the extended π-electron system, a state which can be regarded as an electrostatically bound electron-hole pair, i.e., an exciton. This pair can swiftly relax to the lowest excited state of the molecule—separated energetically from the ground state by the optical gap energy—by dissipating excess energy through molecular vibrations. But how does this exciton ultimately split to form free charge carriers, for example, in a photodiode or a solar cell? Usually, such a splitting is facilitated by incorporating a potential gradient, which can be achieved by blending suitable materials together in a bulk heterojunction. Alternatively, one can envision splitting the exciton by an electric field—an effect which is easily demonstrated by the photoluminescence (PL) quenching of conjugated polymers.[5–18]

Large electric fields, often on the order of MV/cm, play a central role in the operation of organic light-emitting diodes (OLEDs), where electrons and holes are injected from electrodes. In this case, the carriers can actually capture one another through their mutual electrostatic interaction to form intramolecular excitons, which ultimately give rise to luminescence. In the early years of research into polymer-based optoelectronics, it was not clear whether conjugated polymers behave more like 1D semiconductors with strong dielectric screening, or molecular crystals with weak screening.[19]

Conclusive evidence for the molecular-exciton picture of conjugated polymers was ultimately derived from the response of the fluorescence of polymer films to electric fields, which demonstrates that the luminescence can be strongly quenched.[1,10]

There are several ways to examine the nature of photogeneration of charge carriers in conjugated polymer films: far-infrared absorption features due to the sub-gap transitions that emerge from the dipole associated with the open shell;[20] direct dielectric relaxation measurements in the THz regime combined with photoexcitation;[21] direct photocurrent measurements, which often require an external bias and are not always free of artifacts;[1,22] and delayed luminescence through geminate and non-geminate recombination of carriers.[23–25] Ultimately, the most direct way to probe the presence of a charge-carrier pairs is by identifying its spin signature in magnetic resonance experiments.[26–39] Charge-carrier photogeneration can be followed by photocurrent-detected magnetic resonance or by a modulation of the non-geminate delayed-luminescence contribution by flipping spin species in optically detected magnetic resonance (ODMR).[40,41] In ODMR experiments, typically, electron and hole spin permutation symmetries are inverted, which changes singlets into triplets and vice versa.[41] As the two carrier-pair

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species result in excitonic states with very different radiative recombination yields, changes to the spin states of the excitonic charge-carrier precursor pair ensemble immediately impact the PL quantum yield. Alternatively, ODMR may be performed on spin-1 species, i.e., the triplet excited states, a technique which is, in principle, sensitive down to the single-molecule level. Although there are many examples of electroluminescence-based ODMR and electrically detected magnetic resonance in devices, there are only few reports thus far on PL-based ODMR in an OLED structure.

The result of an external electric field on the PL-based ODMR signal of a conjugated polymer film is not immediately apparent on the one hand, one may expect the field to dissociate charge-carrier pairs, decreasing the precursor pair population, thereby quenching the ODMR signal. The direct quenching of the excitons, which give rise to the PL, does not play a significant role at low charge densities. In contrast, the field itself may increase the dissociation of geminate pairs into free charge carriers, as is evidenced by increased photoconductivity. The clear way of testing these hypotheses is to perform ODMR on a working OLED structure in reverse bias. Surprisingly, this seemingly simple experiment was only reported very recently. Kanemoto et al. demonstrated that the ODMR signal is indeed quenched under reverse biasing of an OLED, and at bias voltages substantially below those for which a reduction in PL intensity is observed due to field-assisted exciton dissociation. The quenching of ODMR was found to correlate with an increase in photocurrent of the OLED structure, implying that charge carriers are indeed removed from the device so that they are no longer available for magnetic resonance-related recombination. However, in a conventional OLED structure, the interaction with charge carriers, e.g., injected under forward bias, provides an additional quenching pathway for both excitons—which are responsible for PL—and exciton precursor states, i.e., the weakly coupled electron-hole pairs. As such, the results presented by Kanemoto et al. raise the question whether it is current quenching or field dissociation that is responsible for the reduction in the ODMR signal. We therefore aim to test the effect of electric fields on the ODMR signal in the absence of photocurrents. We stress that the effect of electric fields on the ODMR response is fundamentally different from the effect of a charge current. In OLED structures, the charges associated with a current irreversibly quench excitons: the carrier-pairs of the excitons are therefore lost irreversibly through nonradiative decay (the singlet-polaron quenching) and are not recovered after a sudden removal of the current.

In contrast, in an electric field, the carrier pairs are stabilized as they cannot be lost to current flow even though recombination is quenched. Removal of the electric field results in a delayed recombination as the carrier pairs are recovered.

Figure 1 shows the hypothesis for the effect of an external electric field on the ODMR signal amplitude. At zero external field, interchain electron-hole pairs exist with different spatial separations and orientations, due to different chain conformations in the solid state (cf. Figure 1a). An external electric field may drive their separation (Figure 1b). In this case, a reduction in the overall ODMR amplitude is to be expected. However, in the presence of an electric field, PL quenching typically results from the spatial dissociation of electrons and holes within an exciton. This dissociation is an intermolecular effect and only occurs in bulk or in films, and not in single polymer chains. The process of PL quenching and the accompanying dissociation can be observed clearly in time-resolved experiments, where the delayed luminescence is detected following a voltage pulse. Such stabilization of charge-carrier pairs in an electric field can serve as a means of storing and temporally gating excitation energy in a polymer film. It is therefore also conceivable that the ODMR signal increases under strong bias voltages. We note that there is compelling evidence in the literature, most notably from single-molecule spectroscopy, that electric fields of order 1 MV cm$^{-1}$ cannot form intrachain carrier pairs. However, these studies, which probe the linear Stark shift in the PL spectrum, do demonstrate a strong solvatochromic response of poly[2athoxy-5-(2-ethylhexyloxy)-p-phenylene vinylene] (MEH-PPV) due to the presence of permanent dipoles. These dipoles with magnitudes of tens of Debye, can give rise to a ferroelectric hysteretic response of the Stark shift and, on the single-chain level, can even randomly switch orientation. Such dipolar effects are generally not considered when describing the operation of OLEDs, solar cells or field-effect transistors, and we refrain here from speculating in detail on their role in the impact of electric fields on the ODMR signal.

2. Experimental Section

The ODMR signal in conjugated polymers at room temperature usually originates from delayed recombination of short-lived intermediate electron-hole pairs which exist either in the singlet or the triplet state. These pairs may recombine to singlet or triplet excitons, which makes charge-carrier recombination fundamentally spin dependent. Under magnetic resonant excitation, the singlet and triplet pair populations are inverted, an effect which can be detected as a change in the fluorescence intensity. A challenge in any magnetic resonance experiment involving electrical leads is to avoid the deterioration of the electromagnetic fields due to the interconnects. This is best achieved.
by using thin-film wiring based on indium tin oxide (ITO) or evaporated metal layers. In addition, the fluorescence of the electrically contacted polymer film needs to be excited by a laser and detected by a photodiode. We found that, given the spatial constraints, commercial cavities for electron-paramagnetic resonance (EPR) are only poorly suited for this challenge. Limitations arise because of the combined challenges of finding a field-effect device scheme which does not significantly distort the resonator eigenmodes when a device is inserted while simultaneously allowing optical access with sufficiently high PL detection efficiency. We therefore designed a magnetic resonance probe-head specifically for the purpose of performing ODMR on organic field-effect device structures, working at sufficiently low magnetic fields to allow unfettered, free-space PL excitation and detection. Figure 2a illustrates the experimental setup, and the device structure is shown in Figure 2b. The device is based on a conventional OLED layout as described in McCamey et al., with the crucial difference being that insulating layers are incorporated after each electrode to prevent charge injection and extraction by the electric field. Such insulation is best achieved with spin-on glass (SOG, Futurrex, Inc.), which can be deposited by spin coating to yield transparent, stable, planar films of thickness 200–500 nm. A first layer of SOG was deposited on a prepatterned ITO strip on a glass substrate, purchased from SPI Supplies (Structure Probe, Inc.). After drying and annealing of the SOG for 10 min at 100 °C, a layer of the conjugated polymer MEH-PPV (purchased from American Dye Source) was spin-coated on top of the SOG layer from a toluene solution. The thickness of this active layer typically was on the order of 100 nm, and after annealing for 10 min at 100 °C, the structure was capped by a second SOG layer to provide electrical isolation from the top electrode, a thermally deposited 150 nm thick layer of aluminum.

We note that the detectability of PL ODMR signals in MEH-PPV films strongly depends on the film-deposition parameters. In preparation for the experiments presented in the following, we studied the ODMR responses for a variety of deposition parameters, including deposition methods, spin frequencies, concentration of the toluene solutions, and annealing temperatures. We found that for the device structures discussed here, a significant ODMR response was consistently seen for MEH-PPV films deposited at room temperature from toluene solution with 10 g L −1 polymer concentration by spin casting with rotation frequencies of 1000–3000 rpm. We prepared several of the devices with and without epoxy encapsulation. In both cases, only small photodegradation effects of the ODMR signals were seen.

The fabricated device structures were placed between the two coils of the iron-core magnet of a Bruker E580 EPR spectrometer to induce Zeeman-splitting of the electron and hole spin states. A radiofrequency (RF) field was applied using a single-turn coil oriented orthogonal to the magnet. Such a single-turn RF coil creates highly inhomogeneous and anisotropic RF field amplitudes, i.e., B1 field strengths, but given the thickness of the photoactive polymer layer—on the order of 100 nm—such inhomogeneity only leads to small distributions of B1 within the volume of the samples studied. Moreover, for the continuous-wave (CW) ODMR experiments reported in the following, weak magnitudes of B1 are used such that the spin resonantly induced singlet-to-triplet transition rates are small compared with both electronic

Figure 2. Electric-field-modulated PL ODMR of a conjugated polymer film. a) The device structure [cf. panel (b)] is placed between two coils of a magnet and RF radiation is supplied from a small single-loop coil. PL is excited in the device structure by irradiation with a laser beam with a wavelength of 405 nm (shown in blue), and the fluorescence (shown in orange) is collected using a photodiode after passing through a dichroic mirror. The sketches on the computer screen illustrate examples of lock-in detected ODMR spectra, plotted as differential PL intensity versus static magnetic field strength. b) The capacitive device structure, which allows application of large electric fields without generating a photocurrent due to the photoexcitation, consists of a layer of ITO, an insulating layer of SOG, the active conjugated polymer material MEH-PPV, another layer of SOG, and an Al layer. The electric field is applied between the Al and ITO electrodes (marked with an arrow). c) Photograph of the probe-head with RF leads, and a close-up view of the sample holder with the RF coil. d) Photograph of the capacitor device. To minimize inductive effects and distortion of the RF field, thin-film Al and ITO wiring is used to contact the pixel. These wires are perpendicular to each other to minimize capacitance and leakage effects. The different colors of the device structure arise from optical interference effects. e) Transients of device current and PL intensity as the voltage is turned on and off for one particular device. The brief current peaks coinciding with the rising and falling edges of the voltage pulse show displacement currents as the capacitor charges and discharges upon turning the voltage on and off, but the PL intensity is not significantly affected by the electric field. ODMR spectra are recorded both with the electric field turned on and off (shaded areas).
transition rates as well as spin relaxation rates. Under such conditions, ODMR signal magnitudes are linear with \( B_1 \) and therefore distributions of \( B_1 \) become irrelevant for the observed ODMR line shapes.\(^{[44]}\) The PL used for ODMR detection was excited by a CW laser diode at a wavelength of 405 nm and a typical power of 15 mW, focused to a 1 mm diameter spot size on the sample, and detected by a silicon photodiode in series with a variable gain high-speed current amplifier (Femto DHPCA-100). As illustrated in Figure 2a, the blue excitation light and the resulting orange fluorescence of the polymer film are separated by a dichroic mirror in the beam path.

Note that the experimental parameters (e.g., RF, microwave power, laser power) were chosen based on the technological constraints. For the given experimental requirements (high optical-collection efficiency from a field-effect device) this turned out to be challenging. As discussed above, the use of dielectric cavity resonators is impractical due to limited optical access, while coplanar waveguide resonators\(^{[50]}\) are unsuitable due to the thin-film gate electrodes of the field-effect devices which would shorten the resonator modes and thus reduce microwave power.

For the ODMR experiments discussed here, the change in PL intensity under RF excitation by an Agilent N5161A MXG signal generator was recorded as a function of Zeeman splitting, i.e., of static magnetic field strength \( B_0 \). As also demonstrated that the ODMR feature of MEH-PPV in PL detection, preventing magnetic resonance effects such as singlet–singlet annihilation, which promotes the build-up of depolarization fields.\(^{[53,54]}\) As shown in the lower panel of Figure 2e, the PL intensity does not change appreciably during application of the electric field. However, we also confirmed that ODMR measurement of PL intensity in ODMR, which typically records changes on the order of 10 ppm, we can only perform PL measurements at high laser-excitation intensities. As shown in the lower panel of Figure 2e, the PL intensity does not change appreciably during application of the electric field.

3. Results and Discussion

The left panel of Figure 3a shows an ODMR spectrum of an MEH-PPV film in a capacitor structure with no electric field applied. When an RF excitation with a frequency of 112 MHz is applied to the sample, a pronounced resonance feature is observed at a static magnetic field of 4.7 mT. The feature has an overall amplitude on the order of 30 ppm. We have previously demonstrated that the ODMR feature of MEH-PPV in PL originates from an electron-hole pair process.\(^{[41,44]}\) This fact is apparent from the evolution of the coherent spin nutation in pulsed-magnetic resonance experiments with driving pulse length: at low driving intensities either electron or hole are in resonance, whereas at high driving powers both precess together, giving rise to a doubling of the Rabi frequency in a spin-beating effect.\(^{[43]}\) As the critical driving power for such beating to occur is determined by the magnetic disorder experienced by the resonant spin species which arises primarily from hyperfine interactions, deuteration of the material offers a facile way to confirm the microscopic pair origin of spin beating in MEH-PPV ODMR.\(^{[43]}\) In addition, the measured Rabi frequency provides an absolute metric of the spin of the resonant species, which is found to be \( s = 1/2\).\(^{[55]}\) What is not immediately apparent is how these spins are actually generated in the film, given the fact that photoabsorption primarily leads to the formation of tightly bound exciton species. It is most likely that a small fraction of excitons disassociate on chemical or structural defects within the material.\(^{[56]}\) Much of this dissociation gives rise to geminate-pair formation, which retains the overall spin of the primary photoexcitation during recombination in delayed luminescence.\(^{[25]}\) However, some carrier pairs may also separate completely to give rise to the intrinsic photoconductivity characteristic of even
We note that the overall modulation of the PL is significant and appears to saturate at larger biases, whereas changes in the PL intensity are insignificant and do not correlate with the applied bias. The inset shows a histogram of the saturation values of the quenching, along with markers denoting the corresponding mean (at 36% quenching) and standard deviation (of 11%).

pristine materials.\cite{1} We note that the overall modulation of the PL signal in ODMR is very small, of order 30 ppm, providing a rough metric for the percentage of pairs contributing to the resonance. Much higher participation levels are found in materials with smaller exciton-binding energies, such as CdS nanoparticles, where modulation amplitudes approach a tenth of a percent.\cite{57}

Electric-field modulated ODMR reveals that, under application of a bias voltage of 150 V, corresponding to an electric field of approximately 1 MV cm$^{-1}$, the ODMR amplitude is almost halved, as shown in Figure 3a (center panel). The ODMR amplitude returns to its original value after removal of the electric field (right panel). (In order to account for changes in ODMR amplitude due to irreversible degradation of the sample, we repeated a measurement at zero field immediately before and after each experiment, cf. Figure 3a. A typical measurement series took ≈1.5 h). From this simple observation two important conclusions can be drawn: under application of an electric field, the population of resonant electron-hole pair species is not increased. Conversely, considering prior PL-quenching experiments at high electric fields, one may have actually expected an enhancement. The fact that the ODMR signal does not increase under an electric field may, however, simply be related to the fact that no PL quenching is observed in these experiments at high fluences: a lack of PL quenching implies no formation of additional carrier pairs available for the resonance. Instead, the reduction of the ODMR signal under an external electric field implies the situation as shown in Figure 1. Either carrier pairs are moved closer together, possibly recombining, and therefore become unavailable for manipulation by magnetic resonance; alternatively, they are pulled apart further by the electric field, thus entirely blocking recombination and therefore suppressing ODMR. As the distribution of carrier pairs in the MEH-PPV film is, to a first approximation, expected to be isotropic, one would not anticipate that an external electric field is able to remove all carrier pairs for ODMR. This is analogous to carrier-pair-based delayed fluorescence in conjugated polymers, where an electric-field pulse leads to both initial enhancement of delayed PL and subsequent suppression.\cite{25} This simple intuitive argument is, however, evidently at variance with the recent report of complete ODMR quenching in OLED devices without insulating layers, suggesting that photocurrent flow can have an additional dramatic impact on the resonant pair population.\cite{45}

We tested eight different devices over a broad field range, as shown in Figure 3b. Although all devices showed a certain degree of ODMR quenching at all applied electric fields, they also exhibit saturation of the quenching magnitude. We extrapolated saturation values of the electric-field-induced quenching $Q_{\text{MAX}}$ by fitting with an exponential function $\Delta I/V = 1 - Q_{\text{MAX}}(e^{-1/V_{\text{sat}}} - 1)$. The fits revealed a variance of the saturation scale $V_{\text{sat}}$, which may be due to variations in the device geometry. The effective electric field may also be affected by screening due to the accumulation of charge carriers at the interfaces.

The inset shows the statistical evaluation of the observed saturation values, which scatter around a mean of 36% with a standard deviation of 11%. Small variations of at most a few percent are observed in the PL intensity, but these may be either positive or negative. Such a variation in the response of the PL intensity to electric fields has been reported previously and has been linked to the change in balance between prompt and delayed PL, carrier-assisted quenching of singlet excitons, and the build-up of space charge.\cite{58} Another significant source of this variation is the variation of the thicknesses of the spin-coated SOG and MEH-PPV layers and their dielectric constants that depend to some degree on the deposition parameters. However, in no case is an increase in the ODMR signal amplitude observed under application of an electric field. Similarly, the magnitude of the ODMR signal...
change is significantly larger than the observed PL changes in all cases which confirms that the observed changes in the ODMR signals are not caused by the changes in the PL intensities under application of the electric field. Finally, in no case did ODMR signal strength disappear entirely as the maximally observed quenching was \( \approx 50\% \).

4. Conclusions

PL-based ODMR is a sensitive technique which can be used to study various materials, including single molecules.\(^{[42,43]}\) Surprisingly, even though the technique has been used to gain insight into spin-dependent recombination processes in materials used for organic electronics,\(^{[42]}\) it has only very recently been applied to actual OLED devices.\(^{[45]}\) In the previous report, complete suppression of ODMR from an OLED was observed under reverse biasing, and this suppression was attributed to assisted escape of all carriers out of the constituent pairs’ mutual Coulomb well.\(^{[45]}\) We find that complete suppression of ODMR is not observed when the photocurrent is inhibited in a capacitor structure with insulating layers. We conclude from this observation that electron-hole carrier pairs, which form the precursor to radiative excitons in OLEDs, are readily quenched by free mobile charges. This conclusion agrees with the suggestion that the strong saturation of light intensity in triplet-exciton-based phosphorescent OLEDs is more closely related to charge-induced dissociation of the exciton precursor pairs rather than triplet–triplet annihilation between excitons.\(^{[59]}\) Once photocurrent is eliminated, a universal saturation of the quenching of the ODMR signal at a finite value is observed, which strongly implies an isotropic distribution of charge-carrier pairs within the conjugated polymer film. We hypothesize that the quenching of the carrier-pair population by charges within an OLED device where the photocurrent is not inhibited is analogous to Auger recombination in inorganic semiconductor crystals and that such a process may therefore play a greater role in conjugated-polymer-based devices such as OLEDs and solar cells than previously anticipated.\(^{[45,60]}\)

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Conflict of Interest

The authors declare no conflict of interest.

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